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SBVS078B - OCTOBER 2006-REVISED AUGUST 2011

4 ppm/°C, 100 µA SOT23-6 SERIES VOLTAGE REFERENCES

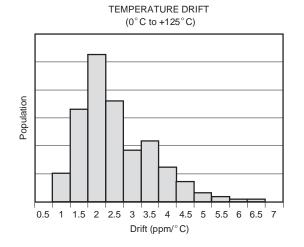
Check for Samples: REF3212-EP, REF3220-EP, REF3225-EP, REF3230-EP, REF3233-EP, REF3240-EP

FEATURES

- Excellent Specified Drift Performance:
 - 7ppm/°C (Max) at 0°C to 125°C
 - 20ppm/°C (Max) at -40°C to 125°C
 - 40ppm/°C (Max) at -55°C to 125°C
- Microsize Package: SOT23-6High Output Current: ±10 mA
- High Accuracy: 0.01%
- Low Quiescent Current: 100 μA
- Low Dropout: 5 mV

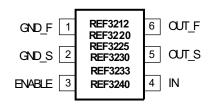
SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

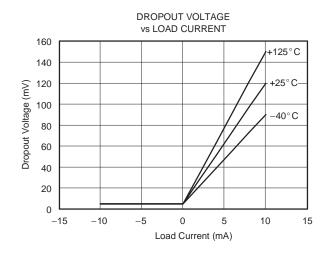
- · Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Military (–55°C/125°C)
 Temperature Range⁽¹⁾
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability
- (1) Additional temperature ranges are available contact factory



APPLICATIONS

- Portable Equipment
- Data Acquisition Systems
- · Medical Equipment
- Test Equipment







Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



DESCRIPTION

The REF32xx is a very low drift, micropower, low-dropout, precision voltage reference family available in the tiny SOT23-6 package.

The small size and low power consumption (120 µA max) of the REF32xx make it ideal for portable and battery-powered applications. This reference is stable with most capacitive loads.

The REF32xx can be operated from a supply as low as 5 mV above the output voltage, under no load conditions. All models are specified for the wide temperature range of –55°C to 125°C.

AVAILABLE OUTPUT VOLTAGES

PRODUCT	VOLTAGE
REF3212	1.25 V
REF3220	2.048 V
REF3225	2.5 V
REF3230	3 V
REF3233	3.3 V
REF3240	4.096 V

Table 1. PACKAGE/ORDERING INFORMATION(1)

PRODUCT	OUTPUT VOLTAGE	PACKAGE-LEAD	PACKAGE DESIGNATOR ⁽²⁾	PACKAGE MARKING
REF3212AMDBVREP	1.25 V	SOT23-6	DBV	R3AM
REF3220AMDBVREP	2.048 V	SOT23-6	DBV	R3BM
REF3225AMDBVREP	2.5 V	SOT23-6	DBV	R3CM
REF3230AMDBVREP	3 V	SOT23-6	DBV	R3DM
REF3233AMDBVREP	3.3 V	SOT23-6	DBV	R3EM
REF3240AMDBVREP	4.096 V	SOT23-6	DBV	R3FM

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

⁽²⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Figure 1. PIN CONFIGURATION

SOT23-6 (TOP VIEW)

GND_F 1 6 OUT_F 5 OUT_S X 4 IN

A. The location of pin 1 on the REF32xx is determined by orienting the package marking as shown.

PIN DESCRIPTIONS

	PIN		
NAME NO.		FUNCTION	DESCRIPTION
ENABLE	3	Digital input	This pin enables and disables the device
GND_F	1	Analog output	Ground connection of the device
GND_S	2	Analog input	Ground sense at the load
IN	4	Analog input	Positive supply voltage
OUT_F	6	Analog output	Output of Reference Voltage
OUT_S	5	Analog input	Sense connection at the load

Absolute Maximum Ratings(1)

		MIN	MAX	UNIT
Input voltage			7.5	V
Output short-circuit		Continuo	ous	
Operating temperature range		-55	125	°C
Storage temperature range	-65	150 ⁽²⁾	°C	
Junction temperature			150	°C
	Human-Body Model	4		137
ESD rating	Charged-Device Model			kV
	Machine Model		400	V

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

⁽²⁾ Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.



Electrical Characteristics

Boldface limits apply over the listed temperature range.

 $T_A = 25$ °C, $I_{LOAD} = 0$ mA, and $V_{IN} = 5$ V (unless otherwise noted)

	PARAMETE		TEST CONDITIONS	MIN	TYP	MAX	UNIT
REF3212	! (1.25 V)					Į.	
	Output voltage			1.2475	1.25	1.2525	V
V_{OUT}	Initial accuracy			-0.2	0.01	0.2	%
NI-1	Output voltage noise		f = 0.1 Hz to 10 Hz		17		μV_{PP}
Noise	Voltage noise		f = 10 Hz to 10 kHz		24		μV_{RMS}
REF3220	(2.048 V)					,	
V		Output voltage		2.044	2.048	2.052	V
V _{OUT}		Initial accuracy		-0.2	0.01	0.2	%
Noise		Output voltage noise	f = 0.1 Hz to 10 Hz		27		μV_{PP}
		Voltage noise	f = 10 Hz to 10 kHz		39		μV_{RMS}
REF3225	(2.5 V)		,				
V _{OUT}	Output voltage			2.495	2.5	2.505	V
*001	Initial accuracy			-0.2	0.01	0.2	%
Noise	Output voltage r	oise	f = 0.1 Hz to 10 Hz		33		μV_{PP}
. 10100	Voltage noise		f = 10 Hz to 10 kHz		48		μV_{RMS}
REF3230	(3 V)						
V _{OUT} Output voltage				2.994	3	3.006	V
VOU1	Initial accuracy			-0.2	0.01	0.2	%
Noise	Output voltage noise Voltage noise		f = 0.1 Hz to 10 Hz		39		μV_{PP}
140100			f = 10 Hz to 10 kHz		57		μV_{RMS}
REF3233	(3.3 V)						
V _{OUT}	Output voltage			3.293	3.3	3.307	V
VOU1	Initial accuracy			-0.2	0.01	0.2	%
Noise	Output voltage r	oise	f = 0.1 Hz to 10 Hz		43		μV_{PP}
110136	Voltage noise		f = 10 Hz to 10 kHz		63		μV_{RMS}
REF3240	(4.096 V)						
V _{OUT}	Output voltage			4.088	4.096	4.104	V
VOU1	Initial accuracy			-0.2	0.01	0.2	%
Noise	Output voltage r	oise	f = 0.1 Hz to 10 Hz		53		μV_{PP}
140136	Voltage noise		f = 10 Hz to 10 kHz		78		μV_{RMS}
REF3212	/REF3220/REF32	25/REF3230/REI	F3233/REF3240				
d\/~/dT	Output voltage to	emperature drift	$T_A = 25^{\circ}C$		4	7	ppm/°C
u v OUT/U I	Output voltage to	emperature unit	-55°C ≤ T _A ≤ 125°C		10.5	40	ррпі/ С
	Long-term stabil	ity	0 tp 1000 h		55		ppm
	Line regulation		$V_{OUT} + 0.05^{(1)} \le V_{IN} \le 5.5 \text{ V}$	– 65	15	65	ppm/V
dV _{OUT} /	Load	Sourcing	$0 \text{ mA} < I_{LOAD} < 10 \text{ mA}, V_{IN} = V_{OUT} + 250 \text{ mV}^{(1)}$	– 40	3	40	u\//m^
dl _{LOAD}	regulation (2)	Sinking	$-10 \text{ mA} < I_{LOAD} < 0 \text{ mA}, V_{IN} = V_{OUT} + 100 \text{ mV}^{(1)}$	-60	20	60	μV/mA
	Thermal	First cycle			100		
dT	hysteresis (3)	Additional cycles			25		ppm
V _{IN} – V _{OUT}	Dropout voltage	(1)	25°C ≤ T _A ≤ +125°C		5	50	mV

- (1) The minimum supply voltage for the REF3212 is 1.8 V.
- (2) Load regulation is using force and sense lines; see the Load Regulation section for more information.
- (3) Thermal hysteresis procedure is explained in more detail in the Applications Information section.



Electrical Characteristics (continued)

Boldface limits apply over the listed temperature range.

 $T_A = 25$ °C, $I_{LOAD} = 0$ mA, and $V_{IN} = 5$ V (unless otherwise noted)

PARAMETER		R	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{LOAD}	AD Output current		$V_{IN} = V_{OUT} + 250 \text{ mV}^{(1)}$	-10		10	mA
	Short-circuit	Sourcing			50		A
I _{SC}	current	Sinking			40		mA
	Turn-on settling	time	0.1% at $V_{IN} = 5 \text{ V with } C_L = 0$		60		μs
V_L	Enable/shutdow	··· (4)	Reference in shutdown mode	0		0.7	V
V _H	Enable/shuldow	(II ()	Reference is active	1.5		V_{IN}	V
V _{IN}	Power supply V	oltage	I _L = 0	V _{OUT} + 0.05 ⁽¹⁾		5.5	V
IQ	Power supply C	urrent	I _L = 0, ENABLE > 1.5 V		100	120	μΑ
	0		–55°C ≤ T _A ≤ 125°C		115	135	μΑ
IS	Overtemperatur	e snutdown	ENABLE < 0.7 V		0.1	1	μΑ
		Specified		-55		125	°C
	Temperature range	Operating		-55		125	C
	rango	Storage		-65		150	
θ_{JA}	Thermal resista	nce, SOT23-6			200		°C/W

⁽⁴⁾ If the rise time of the input voltage is less than or equal to 2ms, the ENABLE and IN pins can be tied together. For rise times greater than 2ms, see the Supply Voltage section.

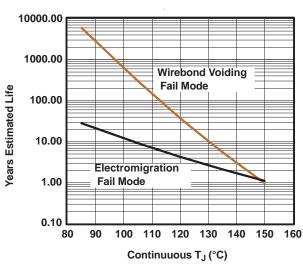


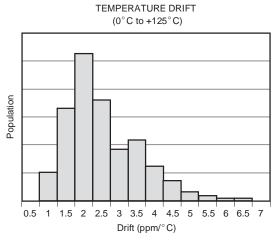
Figure 2. Operating Life Derating Chart

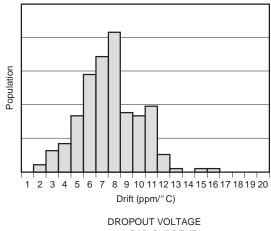
- A. See Datasheet for Absolute Maximum and Minimum Recommended Operating Conditions.
- B. Silicon Operating Life Design Goal is 10 years at 105°C Junction Temperature (does not include package interconnect life).
- C. Enhanced Plastic Product Disclaimer Applies.



TYPICAL CHARACTERISTICS

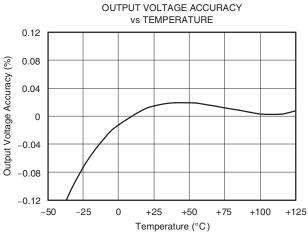
 $T_A = 25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = 5$ V power supply, REF3225 is used for typical characteristics (unless otherwise noted)

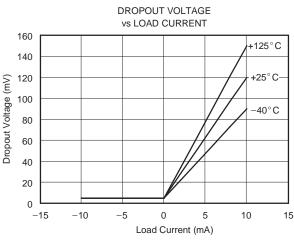


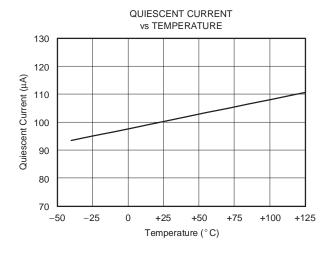


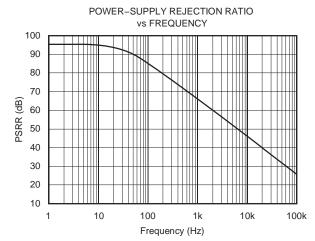
TEMPERATURE DRIFT

 $(-40^{\circ} \text{ C to } +125^{\circ} \text{ C})$





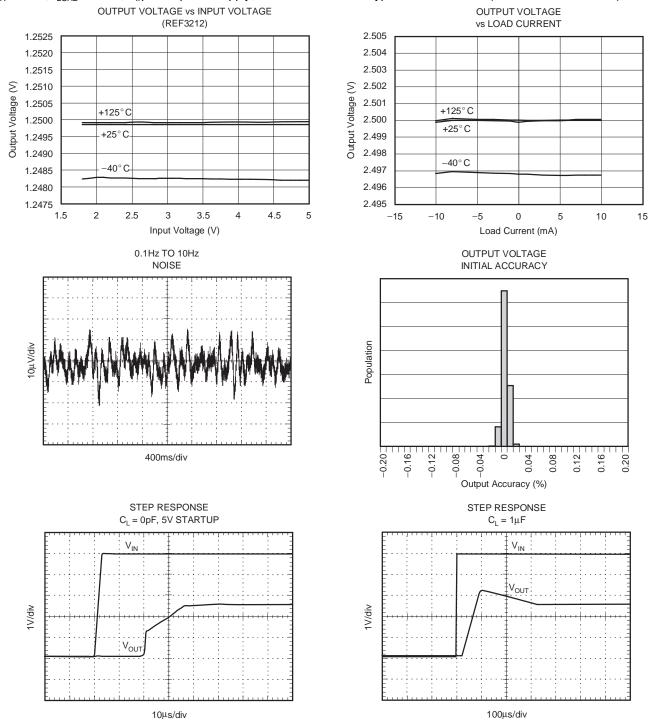






TYPICAL CHARACTERISTICS (continued)

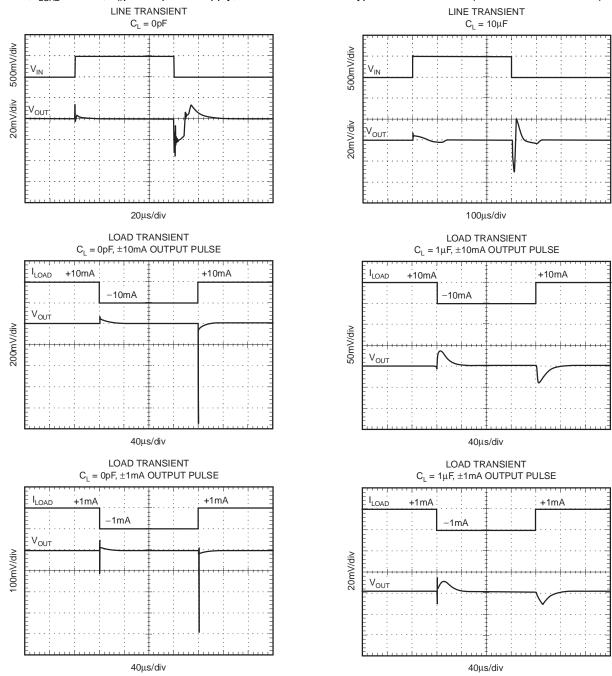
 $T_A = 25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = 5$ V power supply, REF3225 is used for typical characteristics (unless otherwise noted)





TYPICAL CHARACTERISTICS (continued)

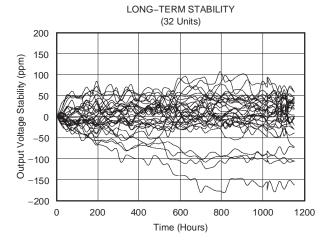
 $T_A = 25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = 5$ V power supply, REF3225 is used for typical characteristics (unless otherwise noted)





TYPICAL CHARACTERISTICS (continued)

 $T_A = 25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = 5$ V power supply, REF3225 is used for typical characteristics (unless otherwise noted)





THEORY OF OPERATION

The REF32xx is a family of CMOS, precision bandgap voltage references. Figure 3 shows the basic bandgap topology. Transistors Q_1 and Q_2 are biased so that the current density of Q_1 is greater than that of Q_2 . The difference of the two base-emitter voltages (Vbe₁ – Vbe₂) has a positive temperature coefficient and is forced across resistor R_1 . This voltage is amplified and added to the base-emitter voltage of Q_2 , which has a negative temperature coefficient. The resulting output voltage is virtually independent of temperature.

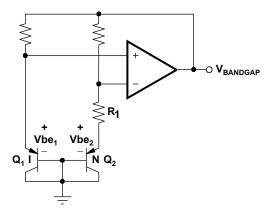


Figure 3. Simplified Schematic of Bandgap Reference



APPLICATION INFORMATION

The REF32xx does not require a load capacitor and is stable with most capacitive loads, see Load Capacitance Guidelines. Figure 4 shows typical connections required for operation of the REF32xx. A supply bypass capacitor of 0.47 µF is recommended.

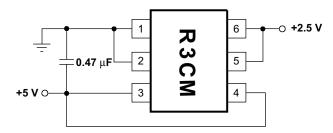


Figure 4. Typical Operating Connections for the REF3225

Supply Voltage

The REF32xx family of references features an extremely low dropout voltage. With the exception of the REF3212, which has a minimum supply requirement of 1.8 V, these references can be operated with a supply of only 5 mV above the output voltage in an unloaded condition. For loaded conditions, a typical dropout voltage versus load is shown in the Typical Characteristic curves.

The REF32xx also features a low quiescent current of 100 μ A, with a maximum quiescent current over temperature of just 135 μ A. The quiescent current typically changes less than 2 μ A over the entire supply range, as shown in Figure 5.

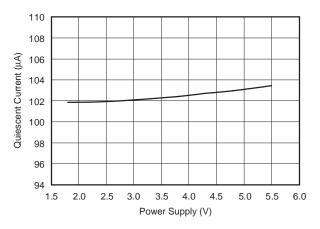


Figure 5. Supply Current vs Supply Voltage

Supply voltages below the specified levels can cause the REF32xx to momentarily draw currents greater than the typical quiescent current. This momentary current draw can be prevented by using a power supply with a fast rising edge and low output impedance.

For optimal startup when the IN pin and ENABLE pin are tied together, keep the input voltage rise time less than or equal to 2ms. For rise times greater than 2ms, the ENABLE pin must be kept below 0.7V until the voltage at the IN pin has reached the minimum operating voltage. One way to control the voltage at the ENABLE pin is with an additional RC filter, such as that shown in Figure 6. The RC filter must hold the voltage at the ENABLE pin below the threshold voltage until the voltage at the input pin has reached the minimum operating voltage.



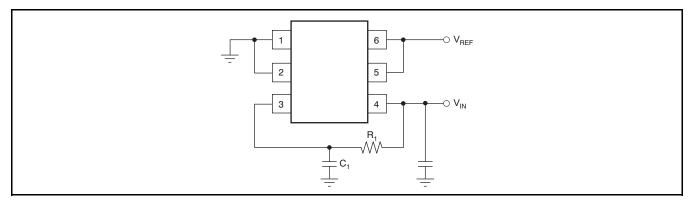


Figure 6. Application Circuit to Control the REF32xx ENABLE Pin

The RC filter in Figure 6 can be used as a starting point for the REF3240. The values for R₁ and C₁ have been calculated so that the voltage at the ENABLE pin reaches 0.7V after the input voltage has reached 4.15V; Table 2 lists these values. For output voltage options other than 4.096V, the RC filter can be made faster.

Table 2. Recommended R₁ and C₁ Values for the REF3240

RISE TIME	R ₁ VALUE	C ₁ VALUE
2ms	150kΩ	100nF
5ms	150kΩ	220nF
10ms	330kΩ	220nF
20ms	390kΩ	330nF
50ms	680kΩ	470nF
100ms	680kΩ	1000nF

In this document, rise time is defined as the time until an exponential input signal reaches 90% of its final voltage. For example, the 2ms value shown in Table 2 is valid for an end value of 5V.

If the input voltage has a different shape or the end value is not 5V, then the time until the minimum dropout voltage has been reached should be used to decide if the IN and ENABLE pins can be tied together. Table 3 lists these times.

Table 3. Minimum Dropout Voltage Times

DEVICE	TIME
REF3212	0.4ms
REF3220	0.5ms
REF3225	0.7ms
REF3230	0.9ms
REF3233	1.0ms
REF3240	1.6ms

Note that because the leakage current of the EN pin is in the range of a few nA, it can be disregarded in most applications.



Shutdown

The REF32xx can be placed in a low-power mode by pulling the ENABLE/SHUTDOWN pin low. When in shutdown mode the output of the REF32xx becomes a resistive load to ground. The value of the load depends on the model, and ranges from approximately 100 k Ω to 400 k Ω .

The ENABLE pin must always be driven to a valid voltage level (V_L or V_H) as shown in the Electrical Characteristics section of this datasheet. To maintain the low quiescent current (100 μ A typ), the ENABLE pin was designed without an internal pull-up resistor. In applications where the shutdown feature will not be used, connecting the ENABLE pin high (to the IN pin) will ensure enabled operation of the device.

Thermal Hysteresis

Thermal hysteresis for the REF32xx is defined as the change in output voltage after operating the device at 25°C, cycling the device through the specified temperature range, and returning to 25°C. It can be expressed as:

$$V_{HYST} = \left(\frac{|V_{PRE} - V_{POST}|}{V_{NOM}}\right) \times 10^{6} (ppm)$$
(1)

Where:

V_{HYST} = Thermal hysteresis (in units of ppm)

 V_{NOM} = The specified output voltage

V_{PRE} = Output voltage measured at 25°C pretemperature cycling

 V_{POST} = Output voltage measured after the device has been cycled through the specified temperature range of -40° C to 125°C and returned to 25°C

Temperature Drift

The REF32xx is designed to exhibit minimal drift error, which is defined as the change in output voltage over varying temperature. The drift is calculated using the box method, as described by the following equation:

$$Drift = \left(\frac{V_{OUTMAX} - V_{OUTMIN}}{V_{OUT} \times Temp Range}\right) \times 10^{6} (ppm)$$
(2)

The REF32xx features a typical drift coefficient of 4 ppm/°C from 0°C to 125°C — the primary temperature range for many applications. For the extended temperature range of –55°C to 125°C, the REF32xx family drift increases to a typical value of 10.5 ppm/°C.

Noise Performance

Typical 0.1-Hz to 10-Hz voltage noise can be seen in the Typical Characteristic curve, 0.1-Hz to 10-Hz Voltage Noise. The noise voltage of the REF32xx increases with output voltage and operating temperature. Additional filtering can be used to improve output noise levels, although care should be taken to ensure the output impedance does not degrade ac performance.

Long-Term Stability

Long-term stability refers to the change of the output voltage of a reference over a period of months or years. This effect lessens as time progresses, as is shown by the long-term stability Typical Characteristic curves. The typical drift value for the REF32xx is 55 ppm from 0 to 1000 hours. This parameter is characterized by measuring 30 units at regular intervals for a period of 1000 hours.



Load Regulation

Load regulation is defined as the change in output voltage as a result of changes in load current. The load regulation of the REF32xx is measured using force and sense contacts, as shown in Figure 7. The force and sense lines can be used to effectively eliminate the impact of contact and trace resistance, resulting in accurate voltage at the load. By connecting the force and sense lines at the load, the REF32xx compensates for the contact and trace resistances because it measures and adjusts the voltage actually delivered at the load.

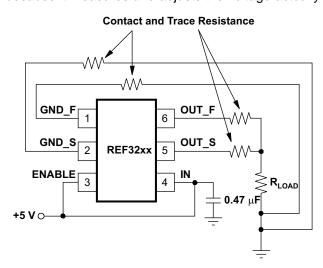


Figure 7. Accurate Load Regulation of REF32xx

The GND_S pin is connected to the internal ground of the device through ESD protection diodes. Because of that connection, the maximum differential voltage between the GND_S and GND_F pins must be kept below 200mV to prevent these dioes from unintentionally turning on.

Load Capacitance Guidelines

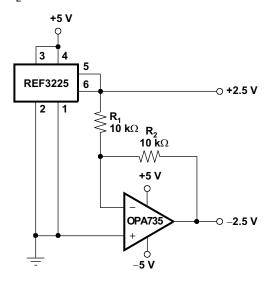
The REF32xx series is designed to be stable with most capacitive loads. Common load capacitance values range between 1 μ F and 47 μ F. To minimize noise and provide specified performance, all models will benefit from an ESR value above 1 Ω with capacitive loads higher than 10 μ F. However, the REF3212 must have an ESR value above 1 Ω with capacitive loads higher than 10 μ F to avoid oscillation.



APPLICATION CIRCUITS

Negative Reference Voltage

For applications requiring a negative and positive reference voltage, the REF32xx and OPA735 can be used to provide a dual-supply reference from a 5-V supply. Figure 8 shows the REF3225 used to provide a 2.5-V supply reference voltage. The low drift performance of the REF32xx complements the low offset voltage and zero drift of the OPA735 to provide an accurate solution for split-supply applications. Care must be taken to match the temperature coefficients of R_1 and R_2 .



Note: Bypass capacitor is not shown.

Figure 8. REF3225 Combined With OPA735 to Create Positive and Negative Reference Voltages

Data Acquisition

Data acquisition systems often require stable voltage references to maintain accuracy. The REF32xx family features stability and a wide range of voltages suitable for most microcontrollers and data converters. Figure 9, Figure 10, and Figure 11 show basic data acquisition systems.

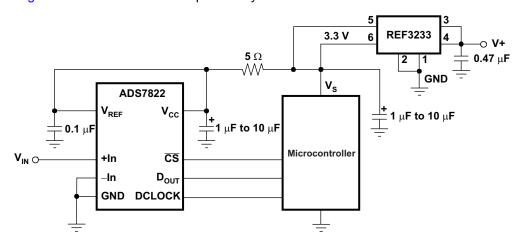


Figure 9. Basic Data Acquisition System 1



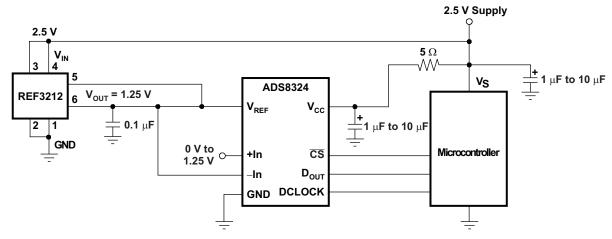


Figure 10. Basic Data Acquisition System 2

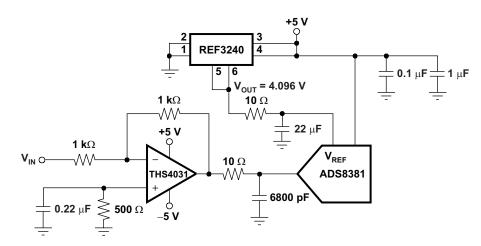


Figure 11. REF3240 Provides an Accurate Reference for Driving the ADS8381





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CI	hanges from Revision A (April 2007) to Revision B	Page
•	Added Pin Descriptions table	3
•	Added note to Enable/Shutdown parameter	5
•	Changed the minimum voltage for Enable/Shutdown with reference active from 0.75 x V _{IN} to 1.5	5
•	Changed current test condition from 0.75 x V _{IN} to 1.5 V	5
•	Added text, two tables and one figure to Supply Voltage section	11
•	Changed pin 3 in Figure 7 from SHDN to ENABLE (typo)	14
•	Added paragraph to Load Regulation section	14

PACKAGE OPTION ADDENDUM



13-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
REF3212AMDBVREP	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3AM	Samples
REF3212AMDBVREPG4	ACTIVE	SOT-23	DBV	6		TBD	Call TI	Call TI	-55 to 125		Samples
REF3220AMDBVREP	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3BM	Samples
REF3225AMDBVREP	ACTIVE	SOT-23	DBV	6		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3CM	Samples
REF3225AMDBVREPG4	ACTIVE	SOT-23	DBV	6		TBD	Call TI	Call TI	-55 to 125		Samples
REF3230AMDBVREP	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3DM	Samples
REF3230AMDBVREPG4	ACTIVE	SOT-23	DBV	6		TBD	Call TI	Call TI	-55 to 125		Samples
REF3233AMDBVREP	ACTIVE	SOT-23	DBV	6		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3EM	Samples
REF3233AMDBVREPG4	ACTIVE	SOT-23	DBV	6		TBD	Call TI	Call TI	-55 to 125		Samples
REF3240AMDBVREP	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3FM	Samples
REF3240AMDBVREPG4	ACTIVE	SOT-23	DBV	6		TBD	Call TI	Call TI	-55 to 125		Samples
V62/07602-01XE	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3AM	Samples
V62/07602-02XE	ACTIVE	SOT-23	DBV	6		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3CM	Samples
V62/07602-03XE	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3DM	Samples
V62/07602-04XE	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3FM	Samples
V62/07602-05XE	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3BM	Samples
V62/07602-06XE	ACTIVE	SOT-23	DBV	6		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-55 to 125	R3EM	Samples

⁽¹⁾ The marketing status values are defined as follows:





13-Jun-2014

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF REF3212-EP, REF3220-EP, REF3225-EP, REF3230-EP, REF3233-EP, REF3240-EP:

Catalog: REF3212, REF3220, REF3225, REF3230, REF3233, REF3240

NOTE: Qualified Version Definitions:





13-Jun-2014

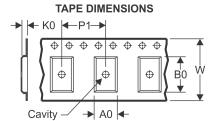
• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 13-Mar-2014

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

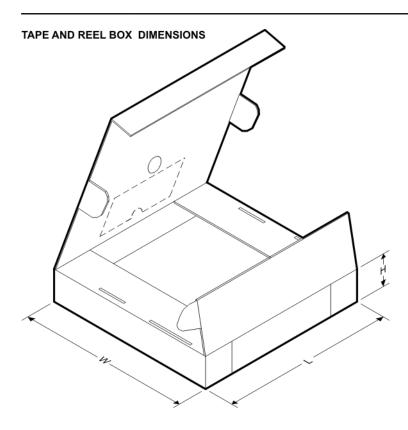
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF3240AMDBVREP	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.1	1.4	4.0	8.0	Q3

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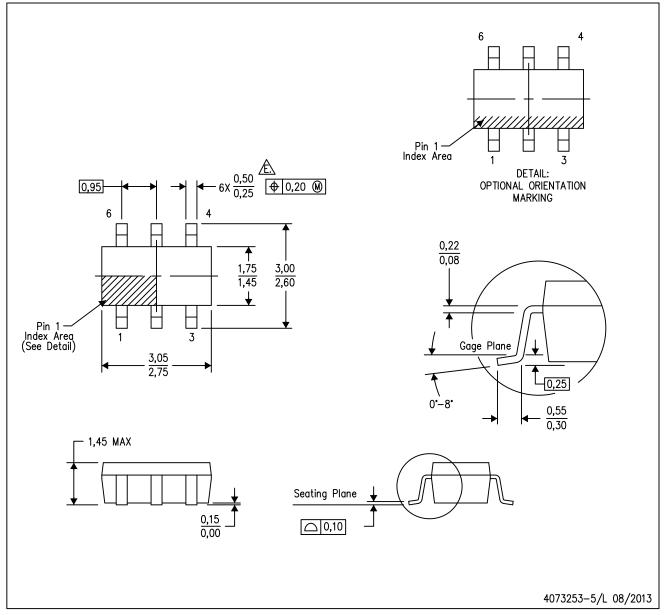


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
REF3240AMDBVREP	SOT-23	DBV	6	3000	210.0	185.0	35.0

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



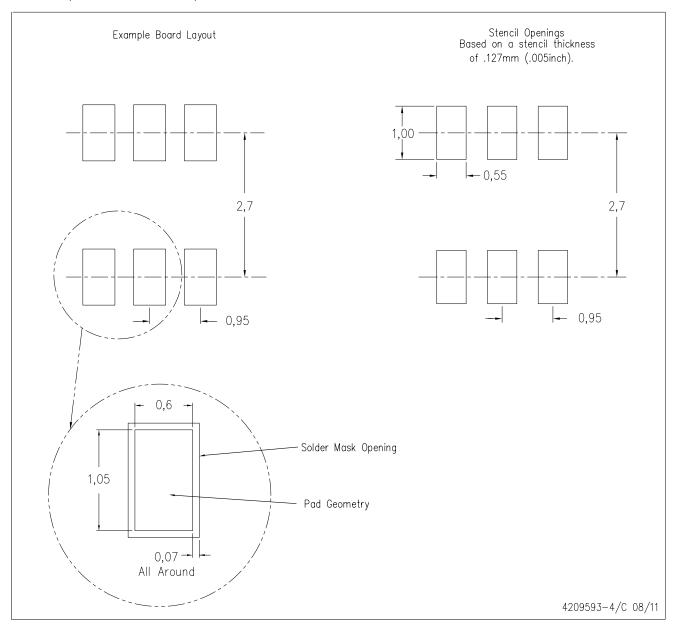
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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